LV5061V

Bi-CMOS IC

Low power consumption and high efficiency Step-down Switching Regulator Controller



Overview

LV5061V is 1ch step-down switching regulator. The operation current is about 90 μ A, and low power consumption is achieved.

Functions

- 1ch SBD rectification controller IC
- Maximum value of light load mode current is 90µA.
- Built-in OCP circuit with P-by-P method
- When P-by-P is generated continuously, it shifts to the HICCUP operation.
- If connect C-HICCUP to GND pin, then latch-off when over current.
- The oscillatory frequency can be set by the external pin. The oscillatory frequency is 300 kHz to 2.2MHz
- Built-in UVLO, TSD

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Input voltage	V _{IN} max		22	V
Allowable pin voltage	PDR,HDRV,RSNS,		VIN	V
	ILIM,EN,PG			
	V _{IN} -PDR		6	V
	REF		6	V
	SS,FB,COMP,		REF	V
	C-HICCUP,RT			
Allowable power dissipation	Pd max	Specified substrate *1	0.74	W
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

*1: Specified substrate 114.3mm×76.1mm×1.6mm³ glass-epoxy

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

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Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Input voltage range	V _{IN}		4.5 to 18	V

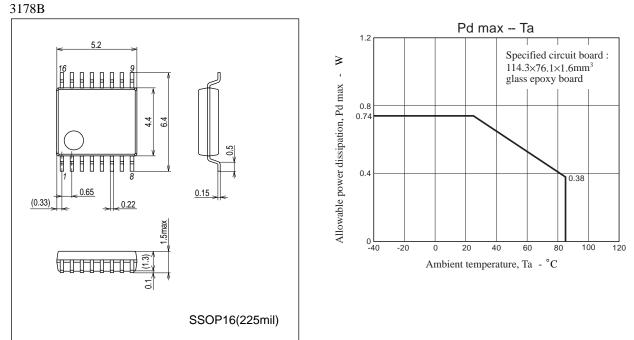
Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{IN} = 15V$

Parameter	Symbol	Conditions	Ratings			Unit
	0,11201		min	typ	max	0.111
Reference voltage						
Internal reference voltage	Vref		1.235	1.260	1.285	V
Pch drive voltage	V _{PDR}	I _{OUT} =0 to -5mA	V _{IN} -5.5	V _{IN} -5.0	V _{IN} -4.5	V
Saw wave oscillator						
Oscillatory frequency	Fosc	RT=470kΩ	280	330	380	kHz
ON/OFF circuit						
IC start-up voltage	VCNT_ON		1.5		VIN	V
Disable voltage	VCNT_OFF				0.3	V
Soft start circuit						
Soft start source current	I _{SS} _SC	EN>1.5V	1.3	2.0	2.7	μΑ
Soft start sink current	I _{SS} _SK	EN>1.5V, I _{LIM} >RSNS SS=4V at HICCUP	1.2	2.0	2.8	mA
UVLO circuit						
UVLO release voltage	VUVLON	FB=COMP	3.0	3.4	3.8	V
UVLO lock voltage	VUVLOF	FB=COMP	2.5	2.9	3.3	V
Error amplifier						
Input bias current	I _{EA} IN		-100	-50	100	nA
Error amplifier gain	G _{EA}		100	250	400	μA/V
Output sink current	I _{EA_} OSK	FB=1.75V	-40	-20	-10	μΑ
Output source current	I _{ES} _OSC	FB=0.75V	10	20	40	μΑ
Over current limit circuit						
Reference current	I _{LIM} 1		48.4	55	61.6	μΑ
Over current detection	V _{LIM_OFS}		-5		+5	mV
comparator offset voltage						
RSNS pin input range	V _{RSNS}		V _{IN} -0.175		V _{IN}	V
HICCUP timer start-up cycle	NLCYCLES			15		cycle
HICCUP comparator threshold voltage	VtHIC		1.2	1.26	1.32	V
HICCUP timer change current	IHIC		1	2	3	μΑ
PWM comparator						
Maximum On-duty	D max		95			%
Logic output				·		
Power good "L" sink current	IPWRGD_L	PG=5V	4	5	6	mA
Power good "H" leakage current	IPWRGD_H	PG=5V			1	μΑ
Power good threshold voltage	V _{tPG}		1.0	1.1	1.2	V
Power good hysteresis	V _{PG} _H		40	50	60	mV
Output		·				
Output on-resistance (High)	R _{ON} H			3		Ω
Output on-resistance (Low)	R _{ON} L			3		Ω
Output on-current (High)	IONH		500			mA
Output on-current (Low)	IONL		500			mA
The entire device		·				
Stand-by current	ICCS	EN<0.3V			1	μΑ
Light load mode consumption current	I _{SLEEP} 1	EN>1.5V, No switching	50	70	90	μA
Thermal shutdown	TSD	*2		170		°C

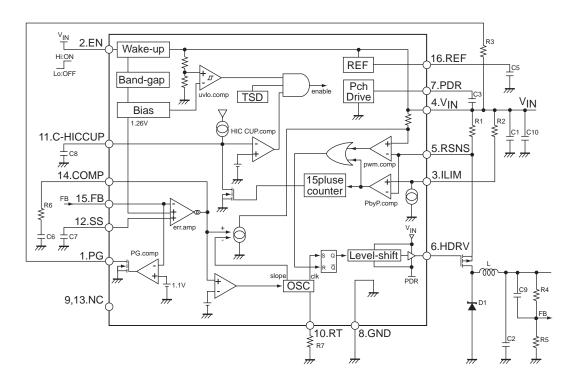
*2: Design certification

Package Dimensions

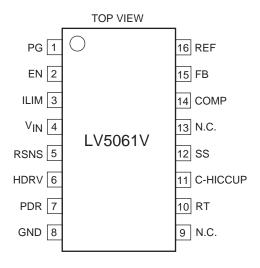
unit : mm (typ)



Block Diagram



Pin Assignment



Pin Descriptions

Pin No.	Pin name	Descriptions	Equivalent circuit
1	PG	Power good pin. Connect to open drain of MOS-FET in ICs inside. Setting output voltage to "L", when FB voltage is 1.05V or less	PG ξ 1kΩ GND
2	EN	ON/OFF pin	VIN 4.8MΩ EN GND GND
3	ILIM	For current detection. Sink current is about 55 μ A. The current limiter comparator works when an external resistor is connected between this pin and V _{IN} , and if the voltage of this resistor is less than the voltage of RSNS then Pch MOS is turned off. This operation is reset each PWM pulse.	
4	VIN	Supply voltage pin. It is observed by the UVLO function. When its voltage becomes 3.4V or more, ICs startup in soft start.	
5	RSNS	Current detection resistor connection pin. Resistor is connected between $V_{\mbox{IN}}$ and this pin, and the current flows to MOSFET are measured.	

Continued on next page.

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Pin No.	Pin name	Descriptions	Equivalent circuit
6	HDRV	The external high-side MOSFET gate drive pin.	VIN ≥130kΩ HDRV PDR
7	PDR	Gate drive voltage of the external Pch MOSFET. Meanwhile, the bypass capacitor is connected between V_{IN} and this pin.	1.1MΩ 1.3MΩ 1.3MΩ 10kΩ 10kΩ 10kΩ GND
8	GND	Ground Pin. Ground pin voltage is reference voltage.	GND GND
9	NC	N.C. pin.	
10	RT	Oscillation frequency setting pin. Resistor is connected between this pin and GND.	VIN 21kΩ ILIM GND
11	C-HICCUP	It is capacitor connection pin for setting re-startup cycle in HICCUP mode. If connect it to GND pin, then latch-off when over current.	
12	SS	Capacitor connection pin for soft start. About 2μA current charges the soft start capacitor.	
13	NC	NC pin.	
14	COMP	Error Amplifier Output Pin. The phase compensation network is connected between GND pin and COMP pin. Thanks to current-mode control, COMP pin voltage would tell you the output current amplitude. COMP pin is connected internally to an int.comparator which comparators with 0.9V reference. If COMP pin voltage is larger than. 0.9V, IC operates in "continuous mode". If COMP pin voltage is smaller than 0.9V, IC operates in "discontinuous mode (low consumption mode)".	VIN

Continued on next page.

Pin No.	Pin name	Descriptions	Equivalent circuit
15	FB	Error amplifier reverse input pin. ICs make its voltage keep 1.26V. Output voltage is divided by external resistors and it across FB.	$\begin{array}{c} V_{\text{IN}} & 10k\Omega \\ \hline 1 k\Omega \\ 1 kD \\ 1 k\Omega$
16	REF	Reference voltage.	$REF \xrightarrow{10\Omega}{10\Omega}$ $REF \xrightarrow{10\Omega}{10\Omega}$ $SIK\Omega \lessapprox 1M\Omega$

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